### NCE P-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE15P25JI uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

● V<sub>DS</sub> =-150V,I<sub>D</sub> =-25A

 $R_{DS(ON)} < 135 m\Omega \bigcirc V_{GS} = -10V \quad (Typ.=120 mR)$ 

 $R_{DS(ON)}$  <160m $\Omega$  @  $V_{GS}$ =-4.5V (Typ.=131mR)

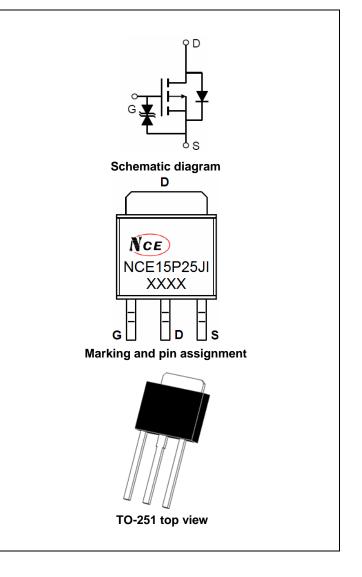
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density cell design for ultra low On-Resistance

### **Application**

Portable equipment and battery powered systems

100% UIS TESTED!

100% ΔVds TESTED!



**Package Marking and Ordering Information** 

- uonage man	.g				
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE15P25JI	NCE15P25JI	TO-251	_	-	-

### Absolute Maximum Ratings (T<sub>c</sub>=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-150	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	-25	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	-17	А
Pulsed Drain Current	I <sub>DM</sub>	-140	А
Maximum Power Dissipation	P <sub>D</sub>	160	W
Derating factor		1.3	W/℃
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C



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# NCE15P25JI

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	R <sub>θJc</sub>	0.8	°C/W	Ī
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### Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-145	-155	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-145V,V <sub>GS</sub> =0V	-	-	1	μA	
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±10	μA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-1.5	-1.9	-3	V	
Drain-Source On-State Resistance	В	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	120	135	mΩ	
Diani-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-20A	-	131	160	11122	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-20A	5	-	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>	\/ - 75\/\/ -0\/	-	7650	-	PF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =-75 $V$ , $V_{GS}$ =0 $V$ , F=1.0MHz	-	148	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WHZ	-	131	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	17	-	nS	
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-75 $V$ , $I_{D}$ =-20 $A$	-	80	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10 $V$ , $R_{GEN}$ =9.1 $\Omega$	-	45	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	65	-	nS	
Total Gate Charge	Qg	\/ - 75\/   - 201	-	137	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-75V, $I_{D}$ =-20A, $V_{GS}$ =-10V	-	25	-	nC	
Gate-Drain Charge	Q <sub>gd</sub>	VGS10V	-	28	-	nC	
Drain-Source Diode Characteristics	<u> </u>		•				
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-25A	-	-	-1.2	V	
Diode Forward Current (Note 2)	Is	-	-	-	-25	Α	
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF =-25A	-	90	-	nS	
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	105	-	nC	

### Notes:

- **1.** Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V<sub>DD</sub>=-75V,V<sub>G</sub>=-10V,L=0.5mH,Rg=25 $\Omega$

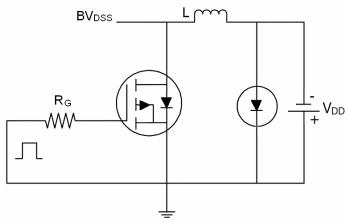
**Pb Free Product** 



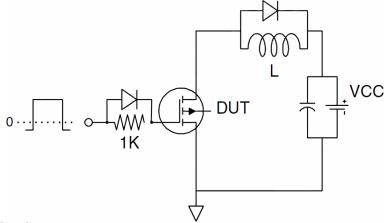
# NCE15P25JI

### **Test Circuit**

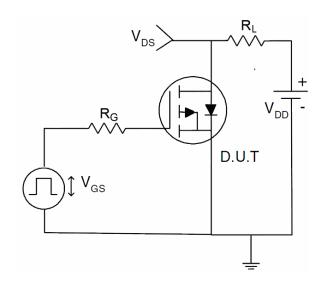
# 1) E<sub>AS</sub> Test Circuit



# 2) Gate Charge Test Circuit

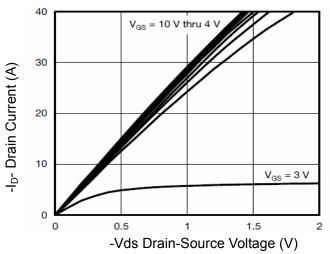


# 3) Switch Time Test Circuit

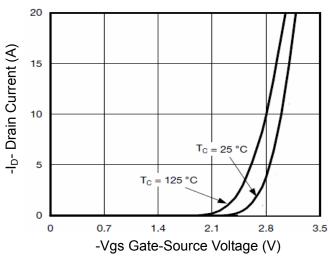




## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

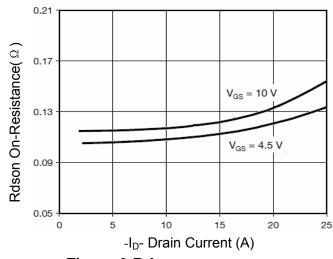


Figure 3 Rdson- Drain Current

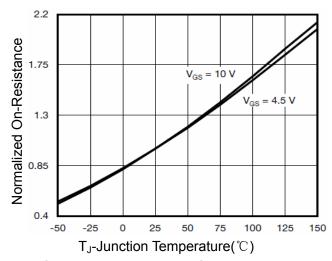


Figure 4 Rdson-JunctionTemperature

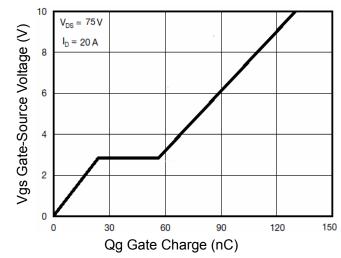


Figure 5 Gate Charge

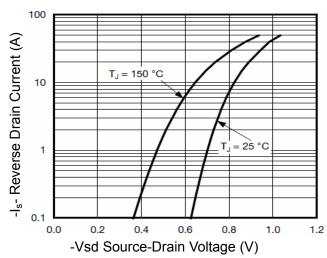


Figure 6 Source- Drain Diode Forward



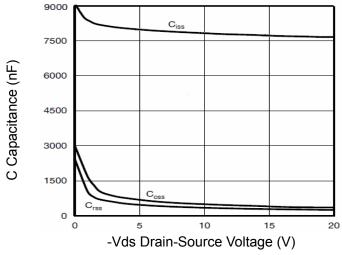
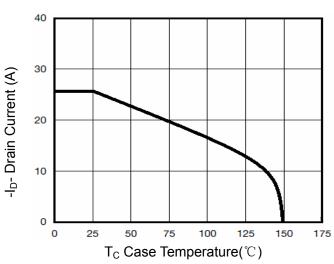
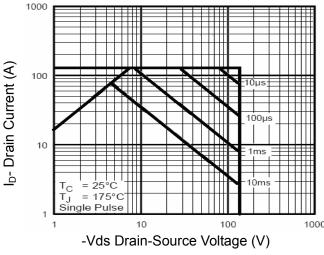


Figure 7 Capacitance vs Vds



**Figure 9 Drain Current vs Case Temperature** 



**Figure 8 Safe Operation Area** 

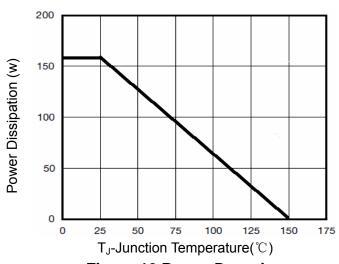
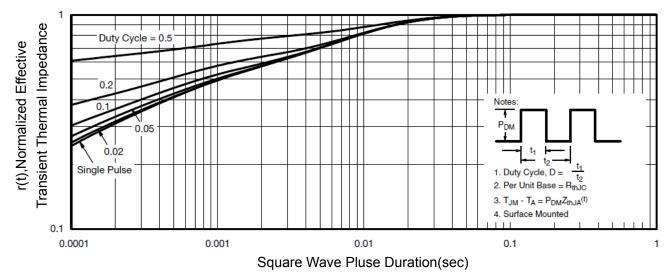


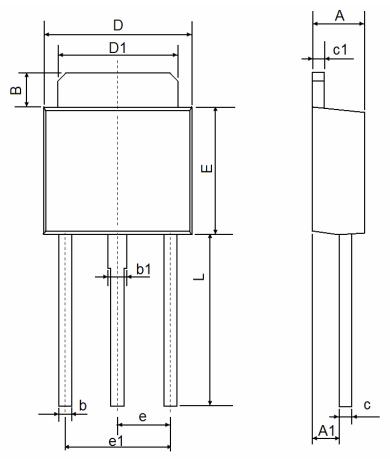
Figure 10 Power De-rating



**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-251 Package Information**



Symbol	Dimensions I	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	1.050	1.350	0.042	0.054	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300 TYP.		0.091	TYP.	
e1	4.500	4.700	0.177	0.185	
L	7.500	7.900	0.295	0.311	



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# NCE15P25JI

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